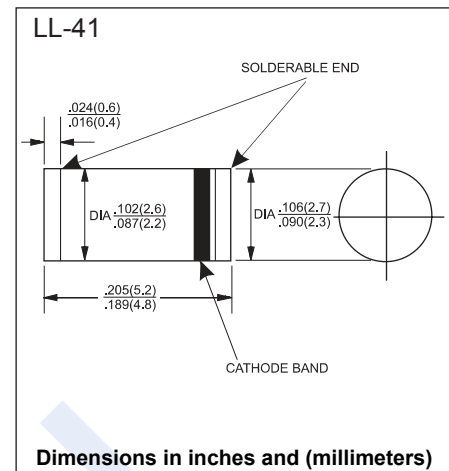


Rectifiers Diodes

KLL4001-KLL4007

■ Features

- Nominal current 1A
- Repetitive peak reverse voltage 50V to 1000V
- Silicon Rectifiers

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Repetitive Peak Reverse Voltage	VRRM	50	V
		100	
		200	
		400	
		600	
		800	
		1000	
Nominal Current with Resistive Load $T_{amb}=25^\circ\text{C}$	IFAV	1	A
Surge Forward Current, 8.3ms Superimposed	IFSM	30	A
Junction Temperature	TJ	175	$^\circ\text{C}$
Junction Storage Temperature Range	Tstg	-65 to 175	$^\circ\text{C}$

■ Electrical Characteristics $T_a = 25^\circ\text{C}$

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Forward voltage	V _F	I _F =1A, T _J =25 $^\circ\text{C}$			1.1	V
Leakage Current	I _R	at VRRM, T _J =25 $^\circ\text{C}$			5	μA